

Amplifier, Power, 1W 3.5-6.5 GHz

#### **Features**

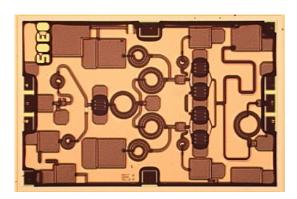
- I Watt Saturated Output Power Level
- Variable Drain Voltage (4-10V) Operation
- ♦ MSAG<sup>™</sup> Process

#### Description

The MAAPGM0029-Die is a 2-stage 1 W power amplifier with on-chip bias networks. This product is fully matched to 50 ohms on both the input and output. It can be used as a power amplifier stage or as a driver stage in high power applications.

Fabricated using M/A-COM's repeatable, high performance and highly reliable GaAs Multifunction Self-Aligned Gate (MSAG<sup>™</sup>) Process, each device is 100% RF tested on wafer to ensure performance compliance.

M/A-COM's MSAG™ process features robust silicon-like manufacturing processes, planar processing of ion implanted transistors, multiple implant capability enabling power, lownoise, switch and digital FETs on a single chip, and polyimide scratch protection for ease of use with automated manufacturing processes. The use of refractory metals and the absence of platinum in the gate metal formulation prevents hydrogen poisoning when employed in hermetic packaging.



### **Primary Applications**

- Wireless Local Loop
- 3.7- 4.2 GHz SatCom

Electrical characteristics. $T_B = 40$ C, $Z_0 = 5022$ , $v_{DD} = 6V$ , $v_{GG} = -2V$ , $P_{in} = 10$ ubiti					
Parameter	Symbol	Typical	Units		
Bandwidth	f	3.5-6.5	GHz		
Output Power	P <sub>OUT</sub>	31	dBm		
Power Added Efficiency	PAE	40	%		
1-dB Compression Point	P1dB	30	dBm		
Small Signal Gain	G	20	dB		
Input VSWR	VSWR	1.5:1			
Gate Current	I <sub>GG</sub>	< 4	mA		
Drain Current	I <sub>DD</sub>	< 400	mA		
Output Third Order Intercept	ΟΤΟΙ	42	dBm		
Noise Figure	NF	7	dB		
2 <sup>nd</sup> Harmonic	2f	-15	dBc		
3 <sup>rd</sup> Harmonic	3f	-25	dBc		

#### Electrical Characteristics: $T_B = 40^{\circ}C^1$ , $Z_0 = 50\Omega$ , $V_{DD} = 8V$ , $V_{GG} = -2V$ , $P_{in} = 16 \text{ dBm}$

#### 1. T<sub>B</sub> = MMIC Base Temperature

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Visit www.macom.com for additional data sheets and product information.



MAAPGM0029-DIE

Preliminary Information

903240 -



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#### MAAPGM0029-DIE 903240 — Preliminary Information

## Maximum Operating Conditions<sup>2</sup>

Parameter	Symbol	Absolute Maximum	Units
Input Power	P <sub>IN</sub>	21.0	dBm
Drain Supply Voltage	V <sub>DD</sub>	+12.0	V
Gate Supply Voltage	V <sub>GG</sub>	-3.0	V
Quiescent Drain Current (No RF)	I <sub>DQ</sub>	470	mA
Quiescent DC Power Dissipated (No RF)	P <sub>DISS</sub>	3.1	W
Junction Temperature	Tj	180	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C

2. Operation outside of these ranges may reduce product reliability. Operation at other than the typical values may result in performance outside the guaranteed limits.

#### **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур	Мах	Unit
Drain Voltage	V <sub>DD</sub>	4.0	8.0	10.0	V
Gate Voltage	$V_{GG}$	-2.3	-2.0	-1.5	V
Input Power	P <sub>IN</sub>		16.0	19.0	dBm
Junction Temperature	Tj			150	°C
MMIC Base Temperature	Τ <sub>B</sub>			Note 2	°C

2. Maximum MMIC Base Temperature = 150°C- 25.5 °C/W \* V<sub>DD</sub> \* I<sub>DQ</sub>

#### **Operating Instructions**

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

- 1. Apply  $V_{GG} = -2 V$ ,  $V_{DD} = 0 V$ .
- 2. Ramp V<sub>DD</sub> to desired voltage, typically 8 V.
- 3. Adjust  $V_{GG}$  to set  $I_{DQ}$ , (approximately @ -2 V).
- 4. Set RF input.
- 5. Power down sequence in reverse. Turn gate voltage off last.



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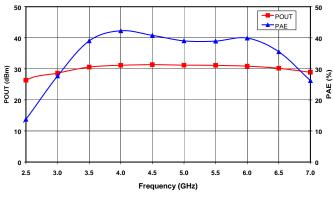


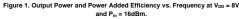
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#### MAAPGM0029-DIE **Preliminary Information**





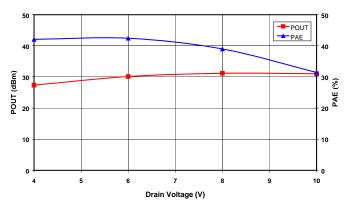


Figure 2. Saturated Output Power and Power Added Efficiency vs. Drain Voltage at fo = 5 GHz.

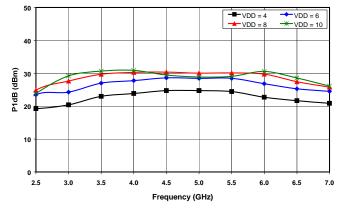


Figure 3. 1dB Compression Point vs. Drain Voltage

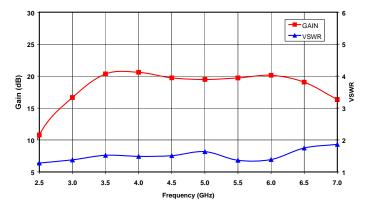


Figure 4. Small Signal Gain and Input VSWR vs. Frequency at  $V_{DD}$  = 8V.

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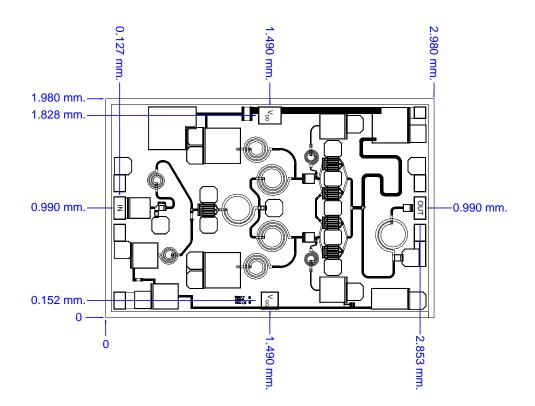


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MAAPGM0029-DIE **Preliminary Information** 

### **Mechanical Information**

Chip Size: 2.980 x 1.980 x 0.075 mm (117x 78 x 3 mils)





Chip edge to bond pad dimensions are shown to the center of the bond pad.

#### **Bond Pad Dimensions**

Pad	Size (μm)	Size (mils)
RF In and Out	100 x 200	4 x 8
DC Drain Supply Voltage VDD	200 x 150	8 x 6
DC Gate Supply Voltage VGG	150 x 150	6 x 6

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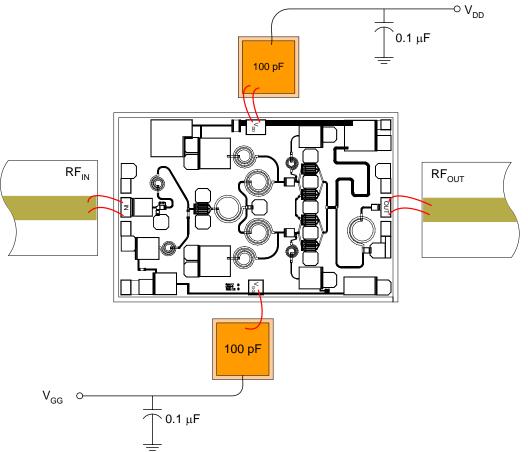


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MAAPGM0029-DIE 903240 — Preliminary Information

#### **Assembly and Bonding Diagram**



**Figure 6. Recommended bonding diagram** for pedestal mount. Support circuitry typical of MMIC characterization fixture for CW test-

#### **Assembly Instructions:**

Die attach: Use AuSn (80/20) 1 mil preform solder. Limit time @ 300 °C to less than 5 minutes.

**Wirebonding:** Bond @ 160 °C using standard ball or thermal compression wedge bond techniques. For DC pad connections, use either ball or wedge bonds. For best RF performance, use wedge bonds of shortest length, although ball bonds are also acceptable.

# Biasing Note: Must apply negative bias to $V_{GG}$ before applying positive bias to $V_{\text{DD}}$ to prevent damage to amplifier.

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